DATA SHEET

Solid State Relay OCMOS FET

PS710A-1A, PS710AL-1A

6-PIN DIP, 0.1Ω LOW ON-STATE RESISTANCE 1.8 A CONTINUOUS LOAD CURRENT 1-ch Optical Coupled MOS FET

DESCRIPTION

NEC

The PS710A-1A and PS710AL-1A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

It is suitable for PLC, etc. because of its large continuous load current and low on-state resistance.

The PS710AL-1A has a surface mount type lead.

FEATURES

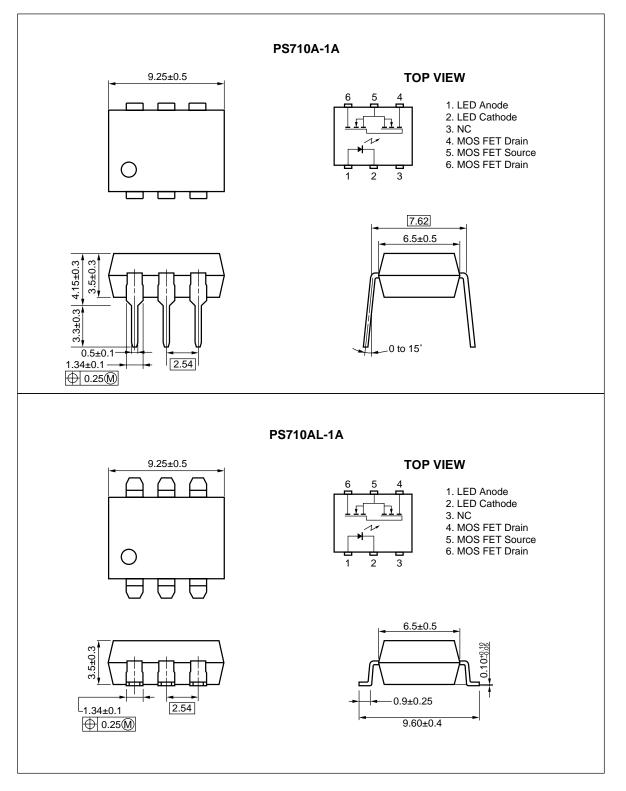
- Low on-state resistance ($R_{on} = 0.1 \Omega$ TYP.)
- Large continuous load current (IL = 1.8 A)
- 1 channel type (1 a output)
- Low LED operating current (IF = 2 mA)
- Designed for AC/DC switching line changer
- Small package (6-pin DIP)
- · Low offset voltage
- PS710AL-1A: Surface mount type

APPLICATIONS

- Measurement equipment
- FA equipment

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

PACKAGE DIMENSIONS (in millimeters)



★ ORDERING INFORMATION

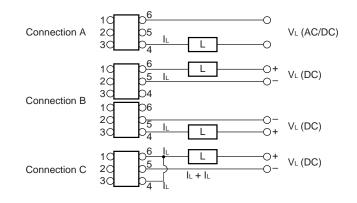
Part Number	Package	Packing Style	Application Part Number ^{*1}
PS710A-1A	6-pin DIP	Magazine case 50 pcs	PS710A-1A
PS710AL-1A			PS710AL-1A
PS710AL-1A-E3		Embossed Tape 1 000 pcs/reel	
PS710AL-1A-E4			

*1 For the application of the Safety Standard, following part number should be used.

Parameter			Symbol	Ratings	Unit
Diode	Forward Current (DC)		IF	50	mA
	Reverse Voltage		VR	5.0	V
	Power Dissipation		PD	50	mW
	Peak Forward Current		IFP	1	А
MOS FET	Break Down Voltage		VL	60	V
	Continuous	Connection A	IL.	1.8	А
	Load Current ^{*2}	Connection B		2.0	
		Connection C		3.6	
	Pulse Load Current ^{'3} (AC/DC Connection)		Ilp	3.6	A
	Power Dissipation		P⊳	560	mW
Isolation Voltage ⁴		BV	1 500	Vr.m.s.	
Total Power Dissipation		Р⊤	610	mW	
Operating Ambient Temperature		TA	-40 to +85	°C	
Storage Temperature		Tstg	-40 to +100	°C	

*1 PW = 100 μ s, Duty Cycle = 1 %

*2 Conditions: IF \geq 2 mA. The following types of load connections are available.



*3 PW = 100 ms, 1 shot

*4 AC voltage for 1 minute at TA = 25 °C, RH = 60 % between input and output

RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

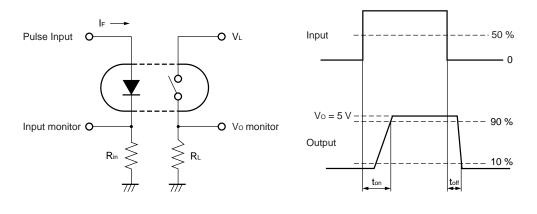
Parameter	Symbol	Symbol MIN.		MAX.	Unit
LED Operating Current	lf	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

ELECTRICAL CHARACTERISTICS (TA = 25 °C)

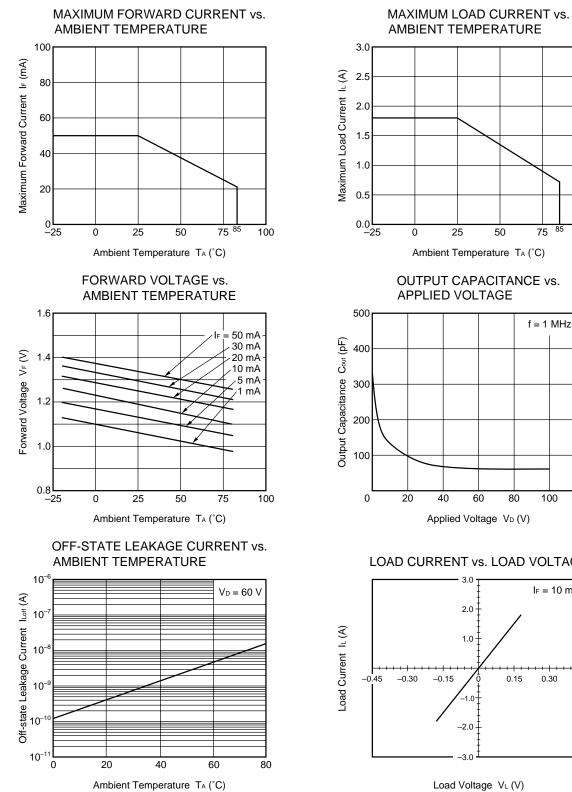
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	iode Forward Voltage		IF = 10 mA		1.2	1.4	V
	Reverse Current	Ir	V _R = 5 V			5.0	μA
MOS FET	Off-state Leakage Current	Loff	V _D = 60 V			1.0	μA
	Output Capacitance	Cout	V _D = 0 V, f = 1 MHz		320		pF
Coupled	LED On-state Current	IFon	I∟ = 1.8 A			2.0	mA
	On-state Resistance	Ron	I_{F} = 10 mA, I_{L} = 1.8 A, t \leq 10 ms		0.1	0.2	Ω
	Turn-on Time [™]	ton	$I_{F} = 10 \text{ mA}, \text{ Vo} = 5 \text{ V}, \text{ RL} = 500 \Omega,$		1.0	3.0	ms
	Turn-off Time ^{*1}	toff	PW ≥ 10 ms		0.05	1.0	
	Isolation Resistance	Ri-o	VI-O = 1.0 kVDC	10 [°]			Ω
	Isolation Capacitance	CI-0	V = 0 V, f = 1 MHz		0.5		pF

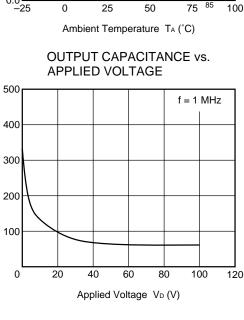
*

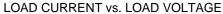
*1 Test Circuit for Switching Time

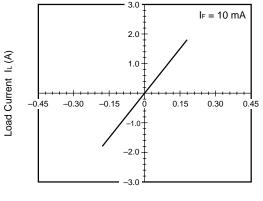


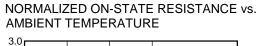
TYPICAL CHARACTERISTICS (TA = 25 °C, unless ot herwise specified) *

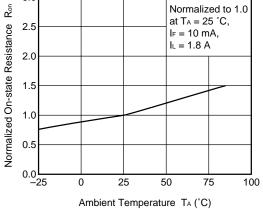




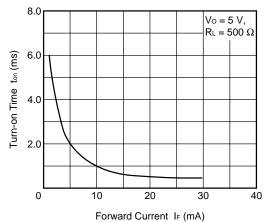




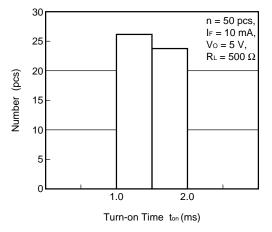




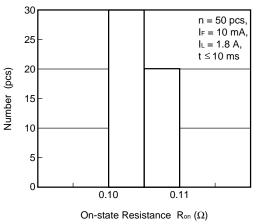
TURN-ON TIME vs. FORWARD CURRENT



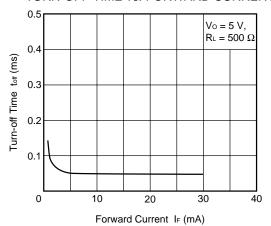
TURN-ON TIME DISTRIBUTION



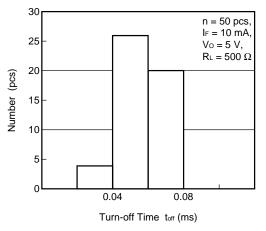
ON-STATE RESISTANCE DISTRIBUTION



TURN-OFF TIME vs. FORWARD CURRENT



TURN-OFF TIME DISTRIBUTION



Normalized to 1.0 at $T_A = 25$ °C,

75

100

I⊧ = 10 mA,

 $V_0 = 5 V,$ $R_L = 500 \Omega$

NORMALIZED TURN-OFF TIME vs.

AMBIENT TEMPERATURE

25

Ambient Temperature T_A (°C)

50

3.0

2.5

2.0

1.5

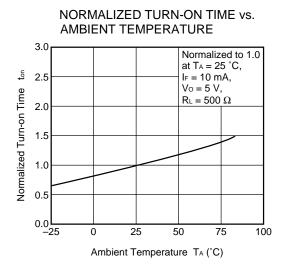
1.0

0.5

0.0

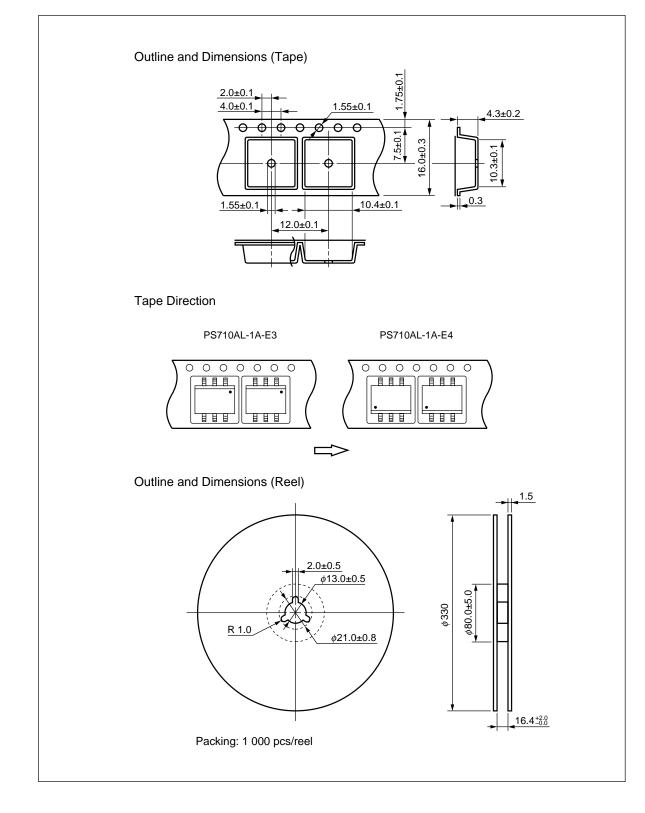
0

Normalized Turn-off Time toff



Remark The graphs indicate nominal characteristics.

***** TAPING SPECIFICATIONS (in millimeters)



★ RECOMMENDED SOLDERING CONDITIONS

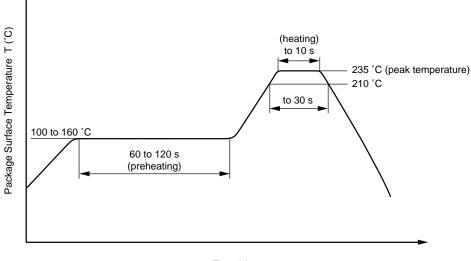
(1) Infrared reflow soldering

- Peak reflow temperature 235 °C or below (package surface temperature)
- Time of temperature higher than 210 °C
- Number of reflows
- Flux

30 seconds or less Two

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow





(2) Dip soldering

Temperature 260 °C or below (molten solder temperature)

- Time
- 10 seconds or less
- Number of times One
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

NEC

[MEMO]

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

• The information in this document is current as of June, 2000. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.

- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC semiconductor products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of customer's equipment shall be done under the full responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
 agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
 risks of damage to property or injury (including death) to persons arising from defects in NEC
 semiconductor products, customers must incorporate sufficient safety measures in their design, such as
 redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:

"Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.

- "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
- "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
- "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note)

(1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.
 (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).

M8E 00.4